

Features

- * High radiant flux
- * Round emitting chip surface
- * Vertical electrode
- * High driving current
- * Most efficient heat dissipation as backside can be soldered directly to heat sink (non-conductive)
- * RoHs and REACH conform

**Applications**

- * Point Source
- * Phototherapy

Optical and Electrical Characteristics @Tambient =25°C

Symbol	Parameter	Min	Typ	Max	Unit	Test conditions
I_F	DC Forward current			1000	mA	
I_{Peak}	Peak Forward current			2000	mA	$T_p < 10\mu\text{sec.}$; $T=1:100$; $R_{\text{therm}} < 100\text{K/W}$
V_F	Forward Voltage	1.4		2.8	V	$I_F = 100\text{mA}$
λ_{Peak}	Peak Wavelength		655		nm	$I_F = 100\text{mA}$
$\Delta\lambda_{0.5}$	Bandwidth of half power		18		nm	$I_F = 20\text{mA}$
t_f	Fall time			100	ns	$I_F = 100\text{mA}$
t_r	Rise time			100	ns	$I_F = 100\text{mA}$
Φ_E	Total Radiant Flux		74		mW	$I_F = 1000\text{mA}$
I_e	Radiant Intensity	1100	1250		mW/sr	$I_F = 1000\text{mA}$
A	Chip Size		2.032		mm ²	
$2\Phi_{0.5}$	Full Emission Angle		27		deg.	
TK_{VF}	Temp.Coeff. Of Forward Voltage		TBA		mV/K	
TK_F	Temp. Coeff. Of Radiant Power		-0.4		%/K	
$T_{Operating}$	Operating Temperature	-40		85	°C	
$T_{Storage}$	Storage Temperature	-40		85	°C	
$T_{Soldering}$	Soldering Temperature			245	°C	Reflow
Q_{j-PIN}	Thermal Resistance		2.3		K/W	
P_{tot}	Total Power Dissipation @ 20mA			2800	mW	

* values only for information

Order information

CQA97312TFW

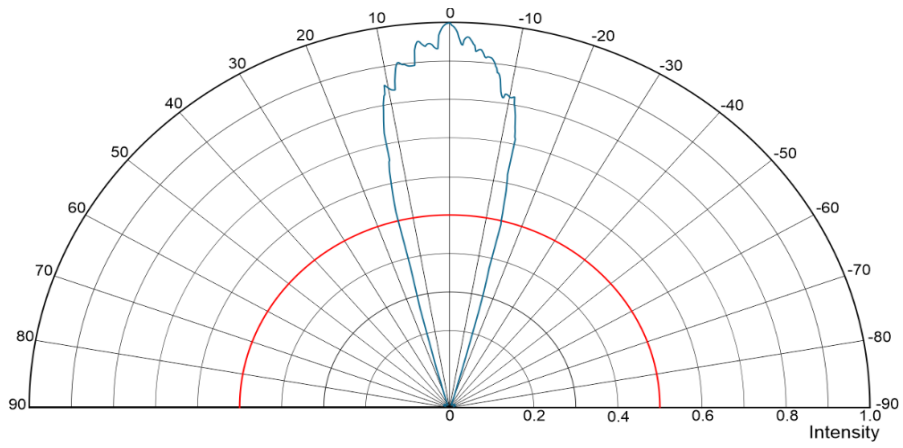
Bulk (20pcs./Bag) / standard

Pls. Contact us for more technical detail information !

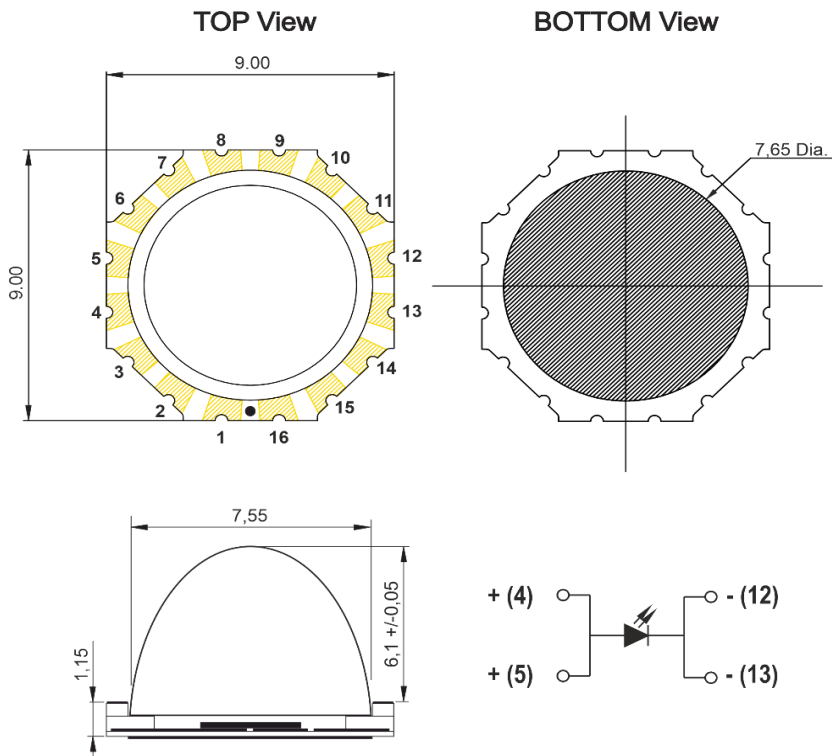
CREATIVE LED GMBH reserves the right to make changes at any time in order to improve design and to supply the best product possible, contact us for latest device specification sheets before using.

Relative Radiation Angle

@20mA @ T_{ambient} = 25°C



Mechanical Drawing



CREATIVE LED GMBH reserves the right to make changes at any time in order to improve design and to supply the best product possible, contact us for latest device specification sheets before using.